International Rectifier

AUTOMOTIVE GRADE

AUIRF2804S-7P

Features

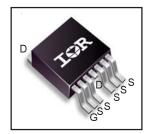
- Advanced Process Technology
- Ultra Low On-Resistance
- 175°C Operating Temperature
- Fast Switching
- Repetitive Avalanche Allowed up to Tjmax
- Lead-Free, RoHS Compliant
- Automotive Qualified *

Description

www.DataShee Specifically designed for Automotive applications, this HEXFET® Power MOSFET utilizes the latest processing techniques to achieve extremely low on-resistance per silicon area. Additional features of this design are a 175°C junction operating temperature, fast switching speed and improved repetitive avalanche rating. These features combine to make this design an extremely efficient and reliable device for use in Automotive applications and a wide variety of other applications.

V _{(BR)DSS}	40V
R _{DS(on)} max.	1.6m Ω
D (Silicon Limited)	320A
I _{D (Package Limited)}	240A

HEXFET® Power MOSFET



G	D	S
Gate	Drain	Source

Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (T_A) is 25°C, unless otherwise specified.

Absolute Maximum Ratings

	Parameter	Max.	Units
I _D @ T _C = 25°C	Continuous Drain Current, V _{GS} @ 10V (Silicon Limited)	320	Α
I _D @ T _C = 100°C	Continuous Drain Current, V _{GS} @ 10V (Silicon Limited)	230	
I _D @ T _C = 25°C	Continuous Drain Current, V _{GS} @ 10V (Package Limited)	240	
I _{DM}	Pulsed Drain Current ①	1360	
P _D @T _C = 25°C	Maximum Power Dissipation	330	W
	Linear Derating Factor	2.2	W/°C
V _{GS}	Gate-to-Source Voltage	± 20	٧
E _{AS}	Single Pulse Avalanche Energy (Thermally Limited) ②	630	mJ
E _{AS} (tested)	Single Pulse Avalanche Energy Tested Value ®	1050	
AR	Avalanche Current ①	See Fig.12a,12b,15,16	Α
E _{AR}	Repetitive Avalanche Energy ®		mJ
TJ	Operating Junction and	-55 to + 175	°C
T _{STG}	Storage Temperature Range		
	Soldering Temperature, for 10 seconds (1.6mm from case)	300	

Thermal Resistance

Thermal redictance								
	Parameter	Тур.	Max.	Units				
$R_{\theta JC}$	Junction-to-Case ®		0.50	°C/W				
R _{ecs}	Case-to-Sink, Flat, Greased Surface	0.50						
$R_{\theta JA}$	Junction-to-Ambient		62					
$R_{\theta JA}$	Junction-to-Ambient (PCB Mount, steady state) ⑦		40	1				

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^{*}Qualification standards can be found at http://www.irf.com/

Static Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
$V_{(BR)DSS}$	Drain-to-Source Breakdown Voltage	40			V	$V_{GS} = 0V, I_D = 250\mu A$
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient		0.028		V/°C	Reference to 25°C, I _D = 1mA
R _{DS(on)} SMD	Static Drain-to-Source On-Resistance		1.2	1.6	mΩ	V _{GS} = 10V, I _D = 160A ③
$V_{GS(th)}$	Gate Threshold Voltage	2.0		4.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
gfs	Forward Transconductance	220			S	$V_{DS} = 10V, I_{D} = 160A$
I _{DSS}	Drain-to-Source Leakage Current			20	μΑ	$V_{DS} = 40V, V_{GS} = 0V$
				250		$V_{DS} = 40V, V_{GS} = 0V, T_{J} = 125^{\circ}C$
I _{GSS}	Gate-to-Source Forward Leakage			200	nA	$V_{GS} = 20V$
	Gate-to-Source Reverse Leakage			-200		$V_{GS} = -20V$

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

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	Parameter	Min.	Тур.	Max.	Units	Conditions
Q_g	Total Gate Charge		170	260	nC	I _D = 160A
Q_{gs}	Gate-to-Source Charge		63		1	$V_{DS} = 32V$
Q_{gd}	Gate-to-Drain ("Miller") Charge		71		1	V _{GS} = 10V ③
t _{d(on)}	Turn-On Delay Time		17		ns	$V_{DD} = 20V$
t _r	Rise Time		150		1	I _D = 160A
$t_{d(off)}$	Turn-Off Delay Time		110		1	$R_G = 2.6\Omega$
t _f	Fall Time		100		1	V _{GS} = 10V ②
L_D	Internal Drain Inductance		4.5		nΗ	Between lead,
						6mm (0.25in.)
L _S	Internal Source Inductance		7.5		1	from package
						and center of die contact
C _{iss}	Input Capacitance		6930		pF	$V_{GS} = 0V$
Coss	Output Capacitance		1750		1	$V_{DS} = 25V$
C _{rss}	Reverse Transfer Capacitance		970		1	f = 1.0MHz, See Fig. 5
Coss	Output Capacitance		5740		1	$V_{GS} = 0V$, $V_{DS} = 1.0V$, $f = 1.0MHz$
C _{oss}	Output Capacitance	T	1570			$V_{GS} = 0V$, $V_{DS} = 32V$, $f = 1.0MHz$
C _{oss} eff.	Effective Output Capacitance		2340		1	$V_{GS} = 0V$, $V_{DS} = 0V$ to 32V

Diode Characteristics

	Parameter	Min.	Тур.	Max.	Units	Conditions
I _S	Continuous Source Current			320		MOSFET symbol
	(Body Diode)				Α	showing the
I _{SM}	Pulsed Source Current			1360		integral reverse
	(Body Diode) ①					p-n junction diode.
V_{SD}	Diode Forward Voltage			1.3	V	$T_J = 25$ °C, $I_S = 160A$, $V_{GS} = 0V$ ③
t _{rr}	Reverse Recovery Time		43	65	ns	$T_J = 25$ °C, $I_F = 160$ A, $V_{DD} = 20$ V
Q_{rr}	Reverse Recovery Charge		48	72	nC	di/dt = 100A/µs ③

Notes:

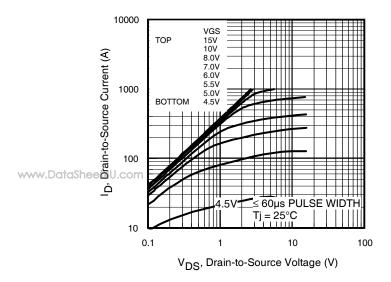
- ① Repetitive rating; pulse width limited by max. junction temperature. (See fig. 11).
- ② Limited by T_{Jmax} , starting $T_J = 25^{\circ}C$, L=0.049mH, $R_G = 25\Omega$, $I_{AS} = 160A$, $V_{GS} = 10V$. Part not recommended for use above this value.
- ③ Pulse width \leq 1.0ms; duty cycle \leq 2%.
- $\ \ \,$ $\ \ \,$ C $_{oss}$ eff. is a fixed capacitance that gives the same charging time as C $_{oss}$ while V $_{DS}$ is rising from 0 to 80% V $_{DSS}$.
- ® This value is determined from sample failure population, starting T_J = 25°C, L=0.049mH, R_G = 25Ω, I_{AS} = 160A, V_{GS} =10V.
- This is applied to D²Pak, when mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994.
- $\ \ \, \mathbb{8} \,\, \mathsf{R}_{\theta} \, \mathsf{is} \, \mathsf{measured} \, \mathsf{at} \, \mathsf{T}_{\mathsf{J}} \, \mathsf{of} \, \mathsf{approximately} \, \mathsf{90}^{\circ} \mathsf{C}.$

Qualification Information[†]

			Automotive				
				(per AEC-Q101) ^{††}			
www.DataShee			Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.				
			D ² Pak 7 Pin MSL1				
		Machine Model	Class M4				
			AEC-Q101-002				
	FOD	Human Body Model	Class H3A				
	Charged Device		AEC-Q101-001				
			Class C5				
		Model	AEC-Q101-005				
RoHS Compliant				Yes			

[†] Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

^{††} Exceptions to AEC-Q101 requirements are noted in the qualification report.



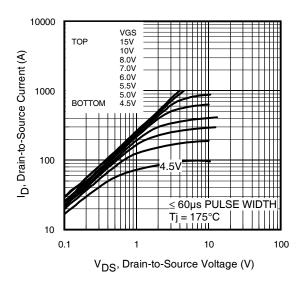
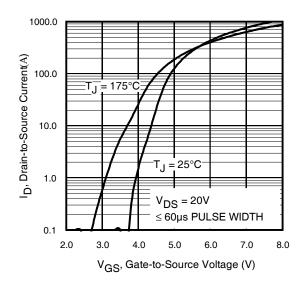


Fig 1. Typical Output Characteristics

Fig 2. Typical Output Characteristics



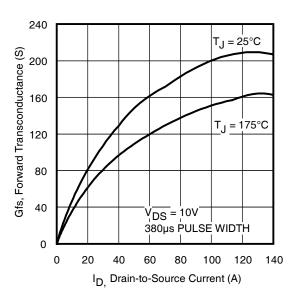
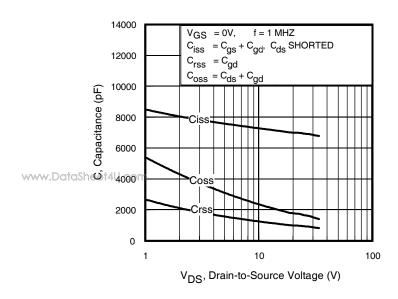


Fig 3. Typical Transfer Characteristics

Fig 4. Typical Forward Transconductance vs. Drain Current

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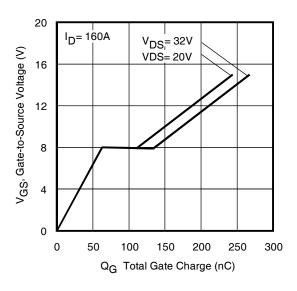
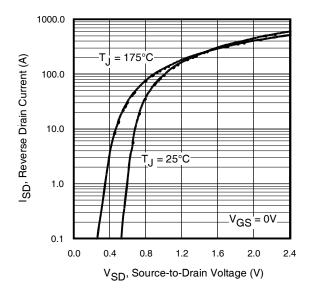


Fig 5. Typical Capacitance vs. Drain-to-Source Voltage

Fig 6. Typical Gate Charge vs. Gate-to-Source Voltage



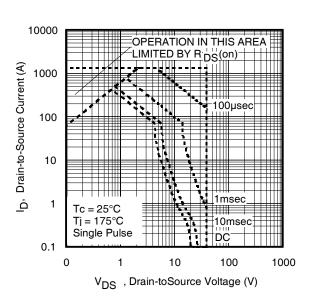
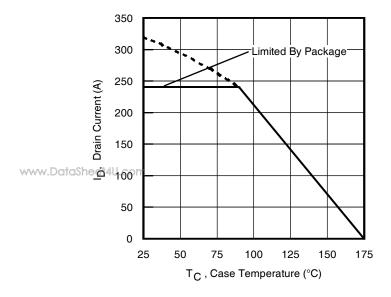


Fig 7. Typical Source-Drain Diode Forward Voltage

nce

Fig 8. Maximum Safe Operating Area

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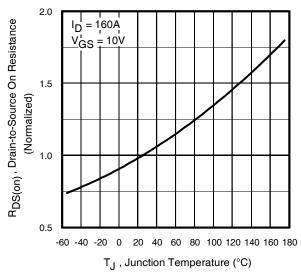


Fig 9. Maximum Drain Current vs. Case Temperature

Fig 10. Normalized On-Resistance vs. Temperature

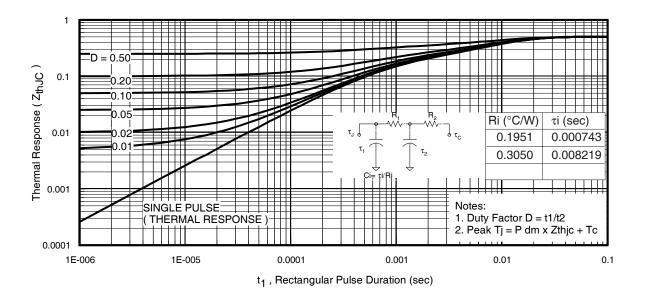


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case

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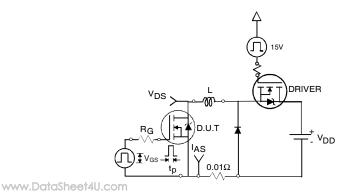


Fig 12a. Unclamped Inductive Test Circuit

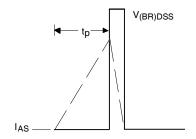


Fig 12b. Unclamped Inductive Waveforms

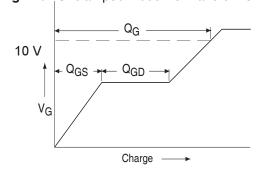


Fig 13a. Basic Gate Charge Waveform

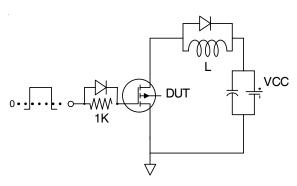


Fig 13b. Gate Charge Test Circuit www.irf.com

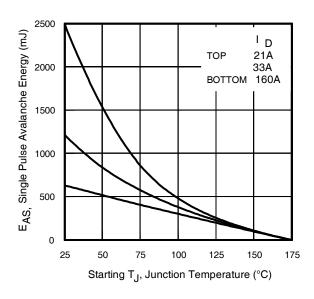


Fig 12c. Maximum Avalanche Energy vs. Drain Current

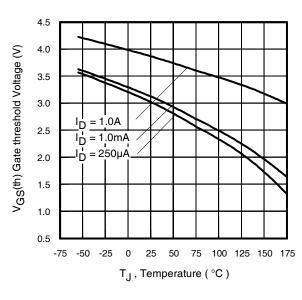


Fig 14. Threshold Voltage vs. Temperature

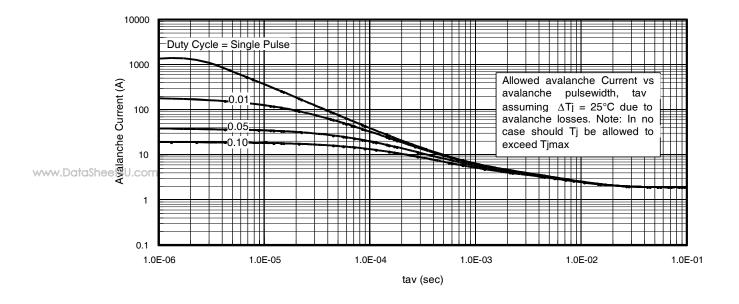


Fig 15. Typical Avalanche Current vs. Pulsewidth

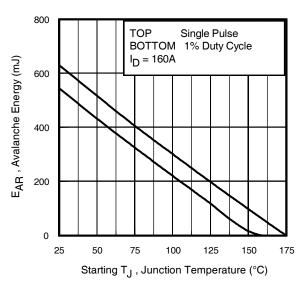


Fig 16. Maximum Avalanche Energy vs. Temperature

Notes on Repetitive Avalanche Curves , Figures 15, 16: (For further info, see AN-1005 at www.irf.com)

- Avalanche failures assumption:
 Purely a thermal phenomenon and failure occurs at a temperature far in excess of T_{jmax}. This is validated for every part type.
- 2. Safe operation in Avalanche is allowed as long asT_{jmax} is not exceeded.
- 3. Equation below based on circuit and waveforms shown in Figures 12a, 12b.
- 4. $P_{D (ave)}$ = Average power dissipation per single avalanche pulse.
- BV = Rated breakdown voltage (1.3 factor accounts for voltage increase during avalanche).
- 6. I_{av} = Allowable avalanche current.
- 7. ΔT = Allowable rise in junction temperature, not to exceed T_{jmax} (assumed as 25°C in Figure 15, 16). t_{av} = Average time in avalanche.
 - D = Duty cycle in avalanche = $t_{av} \cdot f$

 $Z_{thJC}(D, t_{av})$ = Transient thermal resistance, see figure 11)

$$\begin{split} P_{D\;(ave)} &= 1/2\;(\;1.3 \cdot BV \cdot I_{av}) = \triangle T/\;Z_{thJC} \\ I_{av} &= 2\triangle T/\;[1.3 \cdot BV \cdot Z_{th}] \\ E_{AS\;(AR)} &= P_{D\;(ave)} \cdot t_{av} \end{split}$$

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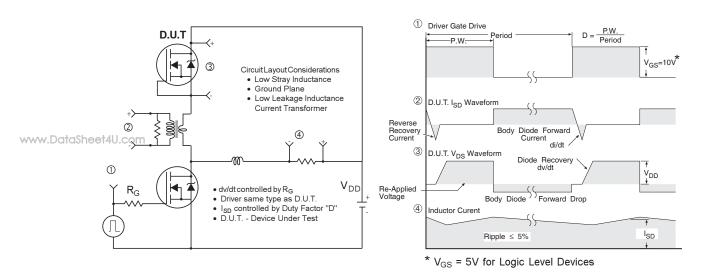


Fig 17. Peak Diode Recovery dv/dt Test Circuit for N-Channel HEXFET® Power MOSFETs

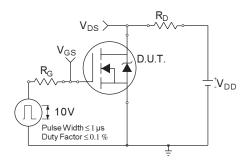


Fig 18a. Switching Time Test Circuit

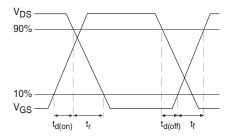


Fig 18b. Switching Time Waveforms

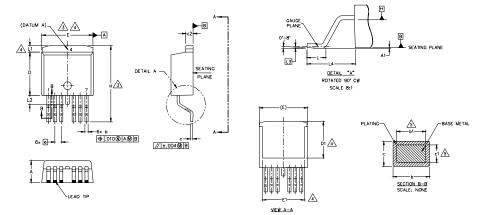
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International

TOR Rectifier

D²Pak - 7 Pin Package Outline

Dimensions are shown in millimeters (inches)



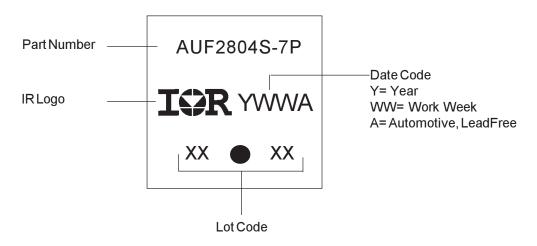
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S	DIMENSIONS					
МВО	B MILLIMETERS		INC	INCHES		
L	MIN.	MAX.	MIN.	MAX.	D T E S	
Α	4,06	4.83	.160	,190		
A1	-	0.254	-	.010		
b	0.51	0.99	.020	.036		
b1	0,51	0.89	.020	.032	5	
с	0.38	0.74	.015	.029		
c1	0.38	0.58	.015	.023	5	
c2	1,14	1.65	.045	.065		
D	8.38	9.65	.330	.380	3	
D1	6.86	-	.270		4	
Ε	9,65	10,67	.380	.420	3,4	
E1	6.22	-	.245		4	
e	1.27	BSC	.050	BSC]	
н	14.61	15.88	.575	.625]	
L	1.78	2.79	.070	.110		
L1	-	1.68	-	.066	4	
L2	-	1.78	-	.070		
L3	0,25	BSC	.010	BSC]	
L4	4,78	5.28	.188	.208		

MOTES.

- 1. DIMENSIONING AND TOLERANCING AS PER ASME Y14,5M-1994
- 2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
- 3. DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.127 [.005] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY AT DATUM H.
- 4. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSION E, L1, D1 & E1.
- 5. DIMENSION 61 AND C1 APPLY TO BASE METAL ONLY.
- 6. DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
- 7. CONTROLLING DIMENSION: INCH.
- 8. OUTLINE CONFORMS TO JEDEC OUTLINE TO-263CB.

D²Pak - 7 Pin Part Marking Information



Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

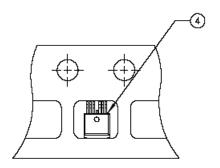
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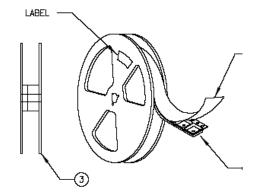
D²Pak - 7 Pin Tape and Reel

NOTES, TAPE & REEL, LABELLING:

- 1. TAPE AND REEL.
 - 1.1 REEL SIZE 13 INCH DIAMETER.
 - 1.2 EACH REEL CONTAINING BOD DEVICES.
 - 1.3 THERE SHALL BE A MINIMUM OF 42 SEALED POCKETS CONTAINED IN THE LEADER AND A MINIMUM OF 15 SEALED POCKETS IN THE TRAILER.
- 1.4 PEEL STRENGTH MUST CONFORM TO THE SPEC. NO. www.DataSheet4U.com $71\!-\!9667.$
 - 1.5 PART ORIENTATION SHALL BE AS SHOWN BELOW.
 - 1.6 REEL MAY CONTAIN A MAXIMUM OF TWO UNIQUE LOT GODE/DATE CODE COMBINATIONS.
 REWORKED REELS MAY CONTAIN A MAXIMUM OF THREE UNIQUE LOT CODE/DATE CODE COMBINATIONS.
 HOWEVER, THE LOT CODES AND DATE CODES WITH THEIR RESPECTIVE QUANTITIES SHALL APPEAR ON THE BAR CODE LABEL FOR THE AFFECTED REEL.



- 2. LABELLING (REEL AND SHIPPING BAG).
 - 2.1 CUST. PART NUMBER (BAR CODE): IRF2804STRL-7P
 - 2.2 CUST. PART NUMBER (TEXT CODE): IRF2804STRL-7P
 - 2.3 I.R. PART NUMBER: IRF2804STRL-7P
 - 2.4 QUANTITY:
 - 2.5 VENDOR CODE: IR
 - 2.6 LOT CODE:
 - 2.7 DATE CODE:



Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

Ordering Information

Base part	Package Type	Standard Pack	Standard Pack	
		Form	Quantity	Complete Part Number
AUIRF2804S-7P	D2Pak 7 Pin	Tube	75	AUIRF2804S-7P
e14U.com				

www.DataSheet

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AUIRF2804S-7P

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IR products are neither designed nor intended for use in automotive applications or environments unless the specific IR products are designated by IR as compliant with ISO/TS 16949 requirements and bear a part number including the designation "AU". Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, IR will not be responsible for any failure to meet such requirements.

For technical support, please contact IR's Technical Assistance Center http://www.irf.com/technical-info/

WORLD HEADQUARTERS:

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